

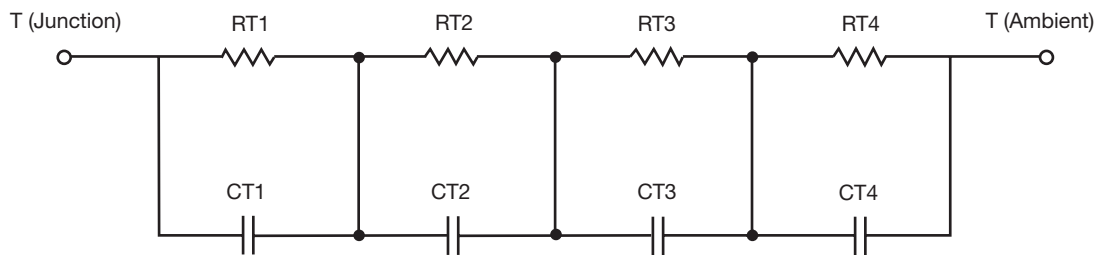
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in P-SPICE, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the P-SPICE Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION

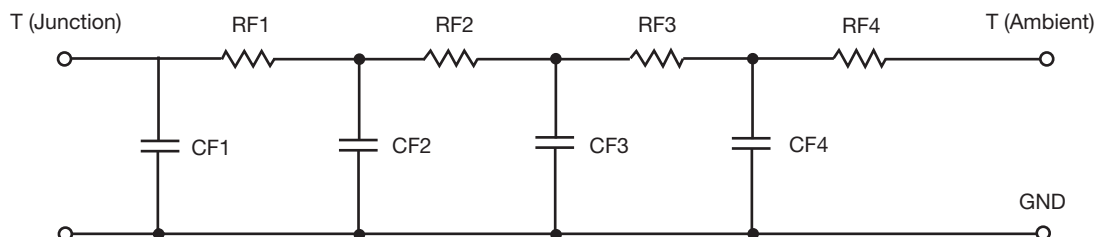


R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	23.6265	N/A	14.0610
RT2	20.9029	N/A	12.8193
RT3	11.1101	N/A	9.0099
RT4	54.3605	N/A	3.9088
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	15.0479m	N/A	78.1808m
CT2	134.0051m	N/A	4.6014m
CT3	1.9097m	N/A	15.3215m
CT4	1.3707	N/A	431.6834u

#### Note

N/A indicates not applicable

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>THERMAL RESISTANCE (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	6.3685	N/A	4.1528
RF2	26.9574	N/A	18.1112
RF3	25.0852	N/A	11.5649
RF4	51.5889	N/A	6.2301
<b>THERMAL CAPACITANCE (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	736.1613u	N/A	370.3832u
CF2	6.1920m	N/A	2.5799m
CF3	78.7658m	N/A	20.6769m
CF4	1.3476	N/A	271.6927m

**Note**

N/A indicates not applicable

